1-to-2 Demultiplexer with **3-State Deselected Output**

The NL7SZ18 is a high-performance non-inverting 1-to-2 demultiplexer. With the Select input [S] at Low, data at A is passed to Y0 and Y1 is set to high impedance. With the Select input [S] at High, data at A is passed to Y1 and Y0 is set to high impedance. The device operates over the voltage range from 1.65 V to 5.5 V.

This device has been optimized for on-board buffering applications and offers mixed (1.65 V, 2.3 V, 3.0 V and 5.5 V) voltage capability by providing over voltage tolerance (OVT*) circuitry on I/O pins.

Features

- High-Speed Propagation Delay t_{PD} 2.5 nS (Typ), Load 50 pF @ 5.0 V
- Power Down Impedance Outputs in High-Z
- Output Drive Capability 32 mA @ 5.0 V
- Broad V_{CC} Operating Range 1.65 V to 5.5 V
- Surface Mount Technology SC-70, 6-Lead and UDFN6 Packaging
- OVT* on Inputs/Outputs
- Pb-Free Package is Available

Typical Applications

- Cell Phones
- PDAs
- Digital Cameras
- Video Cameras

Important Information

- ESD Protection: MM >200 V, Human Body Model >2000 V
- Latch-Up Max Rating: 300 mA
- Pin-to-Pin Compatible with NC7SZ18

*Over Voltage Tolerance (OVT) enables input and output pins to function outside (higher) of their operating voltages, with no damage to the devices or to signal integrity.

PIN/FUNCTION TABLE

Pin	Function			
Α	Data Input			
S	Demultiplexer Select			
Y ₀	Output 1			
Y ₁	Output 2			



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MARKING DIAGRAMS







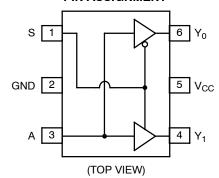


UDFN6 MU SUFFIX CASE 517AA

> LD, T = Device Marking = Date Code* М = Pb-Free Package

(Note: Microdot may be in either location) *Date Code orientation and/or position may vary depending upon manufacturing location.

PIN ASSIGNMENT



TRUTH TABLE

Inp	out	Out	put
S	Α	Y ₀	Y ₁
L	L	L	Z
L	Н	Н	Z
Н	L	Z	L
Н	Н	Z	Н

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
DC Supply Voltage	V _{CC}	-0.5 to +7.0	V	
DC Input Voltage		V _{IN}	-0.5 to +7.0	V
DC Output Voltage		V _{OUT}	-0.5 to +7.0	V
DC Input Diode Current @ V ₁ < -0.5 V		I _{IK}	-50	mA
DC Output Diode Current @ $V_1 < -0.5 V$		lok	-50	mA
DC Output Sink Current		l _{OUT}	±50	mA
DC Supply Current per Supply Pin		I _{CC}	±100	mA
DC Ground Current per Ground Pin	I _{GND}	±100	mA	
Storage Temperature Range	T _{STG}	-65 to +150	°C	
Lead Temperature, 1 mm from Case for 10 Se	econds	TL	260	°C
Junction Temperature Under Bias		TJ	+150	°C
Thermal Resistance (Note 1)		$\theta_{\sf JA}$	250	°C/W
Power Dissipation in Still Air at 85°C		P_{D}	180	mW
Moisture Sensitivity		MSL	Level 1	-
Flammability Rating	Oxygen Index: 28 to 34	F _R	UL 94 V-0 @ 0125 in	-
ESD Withstand Voltage	Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	V _{ESD}	> 2000 > 200 n/a	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.
- 2. Tested to EIA/JESD22-A114-A.
- 3. Tested to EIA/JESD22-A115-A.
- 4. Tested to JESD22-C101-A.

RECOMMENDED OPERATING CONDITIONS

Rating	Symbol	Value	Unit	
DC Supply Voltage		V _{CC}	1.65 to 5.5	V
DC Supply Voltage, Data Retention		V _{CC}	1.5 to 5.5	V
Input Voltage		V_{IN}	0 to 5.5	V
Output Voltage		V _{OUT}	0 to 5.5	V
Operating Temperature		T _A	-40 to 85	°C
Input Rise and Fall Times	$\begin{array}{c} V_{CC} @ 1.8 \pm 0.15 V \\ V_{CC} @ 2.5 \pm 0.2 V \\ V_{CC} @ 3.3 \pm 0.3 V \\ V_{CC} @ 5.0 \pm 0.5 V \end{array}$	t _r , t _f	0 to 20 0 to 20 0 to 10 0 to 5	nS/V
Thermal Resistance		$\theta_{\sf JA}$	350	°C/W

ORDERING INFORMATION

Device Order Number	Package	Shipping [†]
NL7SZ18DFT2	SC70-6	3000 / Tape & Reel
NL7SZ18DFT2G	SC70-6 (Pb-Free)	3000 / Tape & Reel
NL7SZ18MUR2G	UDFN6 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

DC ELECTRICAL CHARACTERISTICS

							v _{cc}			$T_A = 25^{\circ}C$			$T_A = -40^{\circ}C$ to $85^{\circ}C$	
Parameter	Co	ndition	Symbol	(V)	Min	Тур	Max	Min	Max	Unit				
High-Level Input Voltage			V _{IH}	1.65–1.95 2.3–5.5	0.75 V _{CC} 0.70 V _{CC}			0.75 V _{CC} 0.70 V _{CC}		V				
Low-Level Output Voltage			V _{IL}	1.65–1.95 2.3–5.5			0.25 V _{CC} 0.30 V _{CC}		0.25 V _{CC} 0.30 V _{CC}	V				
High-Level Output Voltage	V _{IN} = V _{IH}	I _{OH} = -100 μα	V _{OH}	1.65 2.3 3.0 4.5	1.55 2.20 2.90 4.40	1.65 2.30 3.00 4.50		1.55 2.20 2.90 4.40		V				
		$I_{OH} = -4.0 \text{ mA}$ $I_{OH} = -8.0 \text{ mA}$ $I_{OH} = -16 \text{ mA}$ $I_{OH} = -24 \text{ mA}$ $I_{OH} = -32 \text{ mA}$		1.65 2.3 3.0 3.0 4.5	1.29 1.90 2.40 2.30 3.80	1.52 2.15 2.80 2.68 4.20		1.29 1.90 2.40 2.30 3.80						
Low-Level Output Voltage	V _{IN} = V _{IL}	I _{OL} = 100 μα	V _{OL}	1.65 2.3 3.0 4.5		0.0 0.0 0.0 0.0	0.10 0.10 0.10 0.10		0.10 0.10 0.10 0.10	٧				
		$I_{OL} = 4.0 \text{ mA}$ $I_{OL} = 8.0 \text{ mA}$ $I_{OL} = 16 \text{ mA}$ $I_{OL} = 24 \text{ mA}$ $I_{OL} = 32 \text{ mA}$		1.65 2.3 3.0 3.0 4.5		0.08 0.10 0.15 0.22 0.22	0.24 0.30 0.40 0.55 0.55		0.24 0.30 0.40 0.55 0.55					
Input Leakage Current	V _{IN} = 5.5 V,	GND	I _{IN}	0.0 to 5.5			± 0.1		±1.0	μΑ				
Output High-Z Current	$V_{IN} = V_{IH}$ or $0 < V_{out} \le$		I _{OZ}	1.65 to 5.5			± 0.5		±5.0	μΑ				
Power-Off Leakage Current	V _{IN} or V _{CC}	= 5.5 V	I _{OFF}	0.0			1.0		10	μΑ				
Quiescent Supply Current	V _{IN} = 5.5 V,	GND	I _{CC}	1.8 to 5.5			1.0		10	μΑ				

AC ELECTRICAL CHARACTERISTICS

						T _A = 25°C		T _A = -4		
Parameter	Condition	Figure	Symbol	V _{CC}	Min	Тур	Max	Min	Max	Unit
Propagation Delay A to Y ₀ or Y ₁	C_L = 15 pF R_D = 1.0 M Ω S = OPEN	Figures 1 & 3	t _{PLH} t _{PHL}	$\begin{array}{c} 1.8 \pm 0.15 \\ 2.5 \pm 0.2 \\ 3.3 \pm 0.3 \\ 5.0 \pm 0.5 \end{array}$	2.0 1.0 0.8 0.5	6.3 3.6 2.7 2.0	10.1 5.7 4.0 3.1	2.0 1.0 0.8 0.5	10.5 6.0 4.3 3.3	nS
	$C_L = 50 \text{ pF}$ $R_D = 500 \Omega$ $S = OPEN$	Figures 1 & 3		3.3 ± 0.3 5.0 ± 0.5	1.2 0.8	3.4 2.5	4.9 3.9	1.2 0.8	5.4 4.2	nS
Output Enable Time	$\begin{split} &C_L = 50 \text{ pF} \\ &R_D, R_U = 500 \Omega \\ &S = \text{GND for } t_{PZH} \\ &S = V_{IN} \text{ for } t_{PZL} \\ &V_I = 2 \text{ x } V_{CC} \end{split}$	Figures 1 & 3	t _{PZL} t _{PZH}	1.8 ± 0.15 2.5 ± 0.2 3.3 ± 0.3 5.0 ± 0.5	3.0 1.8 1.2 0.8	6.9 4.2 3.2 2.5	12 6.8 5.0 4.0	3.0 1.8 1.2 0.8	12.5 7.3 5.5 4.3	nS
	$\begin{aligned} &C_L = 50 \text{ pF} \\ &R_D, R_D = 500 \ \Omega \\ &S = \text{GND for } t_{PHZ} \\ &S = V_{IN} \text{ for } t_{PLZ} \\ &V_I = 2 \text{ x } V_{CC} \end{aligned}$	Figures 1 & 3	t _{PLZ} t _{PHZ}	1.8 ± 0.15 2.5 ± 0.2 3.3 ± 0.3 5.0 ± 0.5	2.5 1.5 0.8 0.3	6.0 4.0 2.9 1.8	10 6.8 4.9 3.5	2.5 1.5 0.8 0.3	10.5 7.1 5.3 3.7	nS
Input Capacitance Output Capacitance			C _{IN} C _{OUT}	OPEN 3.3		2.5 4.0				pF
Power Dissipation Capacitance	Note 5	Figure 2	C _{PD}	3.3 5.0		16 19.5				pF

^{5.} C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle (see Figure 2). C_{PD} is related to I_{CCD} dynamic operating current by the expression: I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CCD}static).

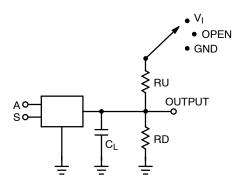


Figure 1. AC Test Circuit

 C_L Includes Load and Stray Capacitance Input PRR = 1.0 MHz; t_W = 500 nS

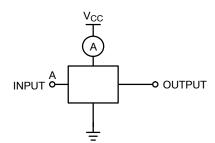
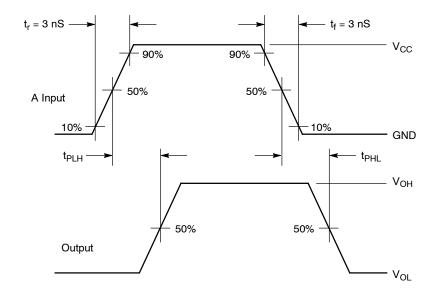


Figure 2. I_{CCD} Test Circuit

 $\begin{aligned} & \text{Input} = \text{AC Waveform; } t_r = t_f = 1.8 \text{ nS} \\ & \text{PRR} = 10 \text{ MHz; } \text{Duty Cycle} = 50\% \\ & \text{S Input} = \text{GND or x} \end{aligned}$



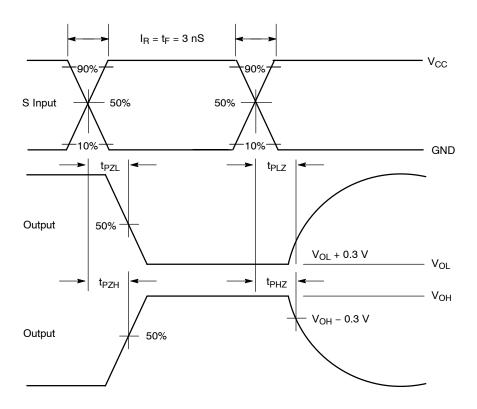
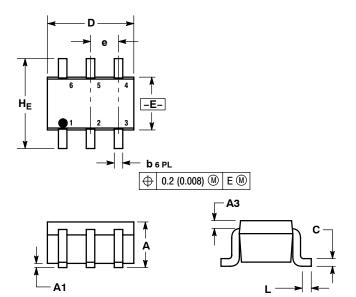


Figure 3. AC Waveforms

PACKAGE DIMENSIONS

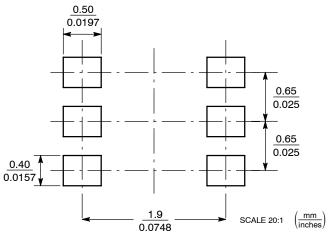
SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE W



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

	MIL	LIMETE	ERS		INCHES	3
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.80	0.95	1.10	0.031	0.037	0.043
A1	0.00	0.05	0.10	0.000	0.002	0.004
АЗ		0.20 RE	F	-	0.008 RI	ΞF
b	0.10	0.21	0.30	0.004	0.008	0.012
С	0.10	0.14	0.25	0.004	0.005	0.010
D	1.80	2.00	2.20	0.070	0.078	0.086
E	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65 BSC			0	.026 BS	С
L	0.10	0.20	0.30	0.004	0.008	0.012
HE	2.00	2.10	2.20	0.078	0.082	0.086

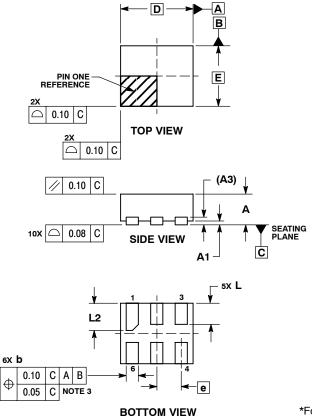
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

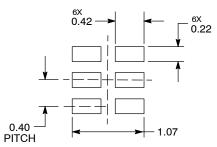
UDFN6, 1.2x1.0, 0.4P CASE 517AA-01 **ISSUE A**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
- DIMENSIONING AND TOLERANCING FER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. DIMENSION 6 APPLIES TO PLATED TERMINAL
- AND IS MEASURED BETWEEN 0.25 AND
- 0.30 mm FROM TERMINAL.
 COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS						
DIM	MIN	MAX					
Α	0.45	0.55					
A1	0.00	0.05					
А3	0.127	REF					
b	0.15	0.25					
D	1.00 BSC						
Е	1.20	BSC					
е	0.40 BSC						
L	0.30	0.40					
L2	0.40	0.50					

MOUNTING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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